

**SINGLE-PHASE GLASS PASSIVATED
MINI FAST RECOVERY SURFACE MOUNT BRIDGE RECTIFIER**
VOLTAGE RANGE 50 to 1000 Volts CURRENT 0.8 Ampere

FEATURES

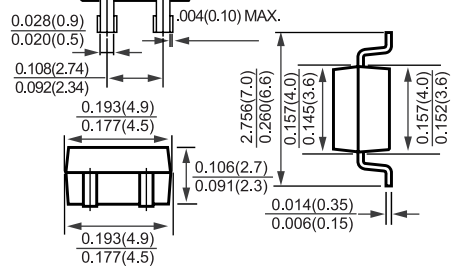
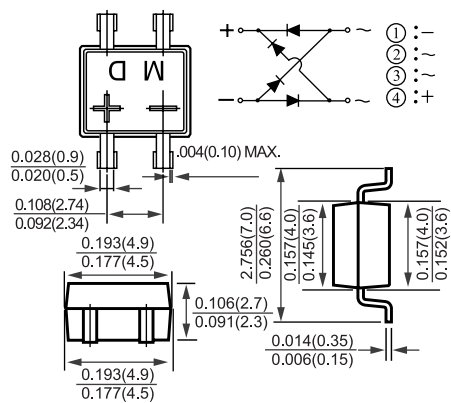
- * Surge overload rating - 30 amperes peak
- * Ideal for printed circuit board
- * Reliable low cost construction utilizing molded
- * Glass passivated device
- * Polarity symbols molded on body
- * Mounting position: Any
- * Weight: 0.5 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.



MD-S



Dimensions in millimeters

MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	FMD1S	FMD2S	FMD3S	FMD4S	FMD5S	FMD6S	FMD7S	UNITS	
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts	
Maximum RMS Bridge Input Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts	
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	Volts	
Maximum Average Forward Output Rectified Current TA = 30°C -on glass-epoxy P.C.B. (NOTE 1) -on aluminum substrate (NOTE 2)	I _O	0.5						0.8		Amp
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	30								Amps
Typical Junction Capacitance (Note3)	C _J	15								pF
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150								°C

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	FMD1S	FMD2S	FMD3S	FMD4S	FMD5S	FMD6S	FMD7S	UNITS	
Maximum Forward Voltage Drop per Bridge Element at 0.4A DC	V _F	1.30								Volts
Maximum Reverse Current at rated	I _R	10								uAmps
DC Blocking Voltage per element		100								uAmps
Maximum Reverse Recovery Time (Note 4)	t _{rr}	150			250		500		nSec	

NOTE: 1. On glass-epoxy P.C.B. mounted on 0.05 X 0.05" (1.3 X 1.3mm) pads.

2. On aluminum substrate P.C.B. with an area of 0.8 X 0.8 X 0.25" (20 X 20 X 6.4mm) mounted on 0.05 X 0.05" (1.27 X 1.27mm) solder pad.

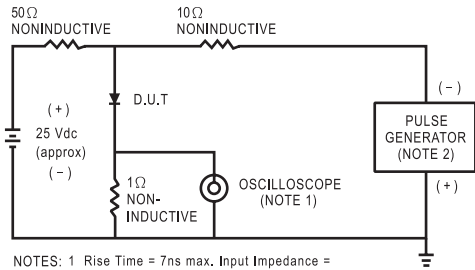
3. Measured at 1MHz and applied reverse voltage of 4.0 volts.

4. Test Conditions: I_F = 0.5A, I_R = 1.0A, I_{RR} = 0.25A.

5. Suffix "-S" Surface Mount for Mini Dip Bridge.

RATING AND CHARACTERISTIC CURVES (FMD1S THRU FMD7S)

FIG. 1 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1 Rise Time = 7ns max. Input Impedance = 1 megohm, 22pF.
2. Rise Time = 10ns max. Source Impedance = 50 ohms.

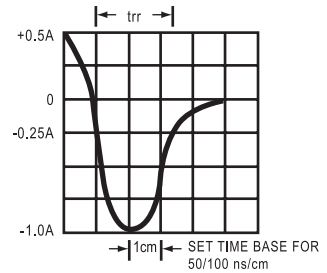


FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

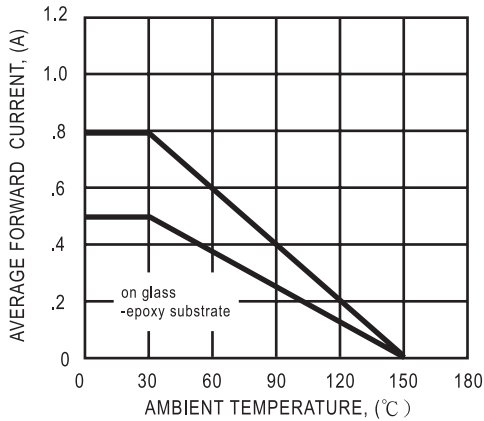


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

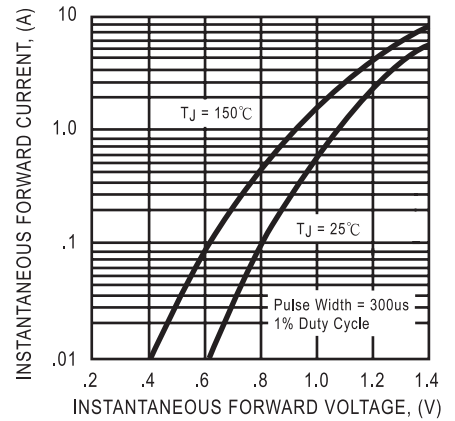


FIG. 4 - TYPICAL JUNCTION CAPACITANCE

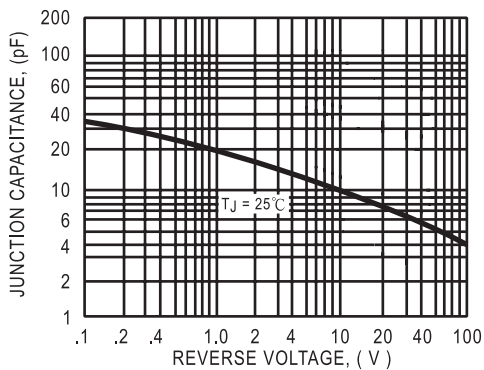


FIG. 3 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

